Preferred Devices

Thyristor Surge Protectors

High Voltage Bidirectional TSPD

These Thyristor Surge Protective devices (TSPD) prevent overvoltage damage to sensitive circuits by lightning, induction and power line crossings. They are breakover—triggered crowbar protectors. Turn—off occurs when the surge current falls below the holding current value.

Secondary protection applications for electronic telecom equipment at customer premises.

- High Surge Current Capability: 50 Amps 10 x 1000 μsec, for Controlled Temperature Environments
- The MMT05B350T3 is used to help equipment meet various regulatory requirements including: Bellcore 1089, ITU K.20 & K.21, IEC 950, UL 1459 & 1950 and FCC Part 68.
- Bidirectional Protection in a Single Device
- Little Change of Voltage Limit with Transient Amplitude or Rate
- Freedom from Wearout Mechanisms Present in Non–Semiconductor Devices
- Fail-Safe, Shorts When Overstressed, Preventing Continued Unprotected Operation
- Surface Mount Technology (SMT)
- **%** Indicates UL Recognized File #E210057
- Device Marking: MMT05B350T3: RPBM

MAXIMUM RATINGS ($T_J = 25^{\circ}C$ unless otherwise noted)

Rating	Symbol	Value	Unit
Off-State Voltage - Maximum	V_{DM}	300	Volts
Maximum Pulse Surge Short Circuit Current Non-Repetitive Double Exponential Decay Waveform (-25°C Initial Temperature) (Notes 1 and 2) 2 x 10 μsec 8 x 20 μsec 10 x 160 μsec 10 x 360 μsec 10 x 560 μsec 10 x 700 μsec	IPPS2 IPPS3 IPPS4 IPPS5 IPPS6	±150 ±150 ±100 ±100 ±70 ±70 ±50	A(pk)
Non-Repetitive Peak On-State Current 60 Hz Full Sign Wave	I _{TSM}	32	A(pk)
Maximum Non–Repetitive Rate of Change of On–State Current Exponential Waveform, < 100 A	di/dt	±300	A/μs

- 1. Allow cooling before testing second polarity.
- 2. Measured under pulse conditions to reduce heating.



ON Semiconductor®

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50 AMP SURGE 350 VOLTS





SMB (No Polarity) (Essentially JEDEC DO-214AA) CASE 403C

MARKING DIAGRAMS



RPBM = Specific Device Code

′ = Year

WW = Work Week

ORDERING INFORMATION

Device	Package	Shipping [†]
MMT05B350T3	SMB	12 mm Tape and Reel (2.5 K/Reel)

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

THERMAL CHARACTERISTICS

Characteristic		Max	Unit
Operating Temperature Range Blocking or Conducting State	T _{J1}	-40 to +125	°C
Overload Junction Temperature – Maximum Conducting State Only		+175	°C
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds		260	°C

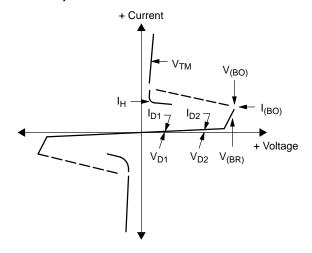
ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}\text{C}$ unless otherwise noted) Devices are bidirectional. All electrical parameters apply to forward and reverse polarities.

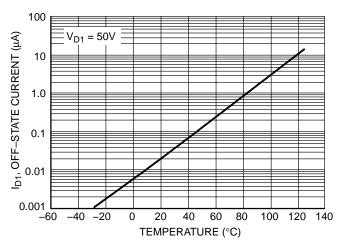
Characteristics	Symbol	Min	Тур	Max	Unit
Breakover Voltage (Both polarities) (dv/dt = 100 V/ μ s, I _{SC} = 1.0 A, Vdc = 1000 V) (+65°C)	V _(BO)	_ _	_ _	400 412	Volts
Breakover Voltage (Both polarities) (f = 60 Hz, I_{SC} = 1.0 A(rms), V_{OC} = 1000 V(rms), R_I = 1.0 k Ω , t = 0.5 cycle) (Note 3)	V _(BO)	_	-	400	Volts
(+65°C)		-	_	412	
Breakover Voltage Temperature Coefficient	$dV_{(BO)}/dT_{J}$	-	0.12	_	V/°C
Breakdown Voltage (I _(BR) = 1.0 mA) Both polarities	V _(BR)	_	350	_	Volts
Off State Current ($V_{D1} = 50 \text{ V}$) Both polarities ($V_{D2} = V_{DM}$) Both polarities	I _{D1} I _{D2}	_ _	_ _	2.0 5.0	μΑ
On–State Voltage (I _T = 1.0 A) (PW ≤ 300 μs, Duty Cycle ≤ 2%) (Note 3)	V _T	-	1.6	3.0	Volts
Breakover Current (f = 60 Hz, V_{DM} = 1000 V(rms), R_S = 1.0 k Ω) Both polarities	I _{BO}	-	475	-	mA
Holding Current (Both polarities) (Note 3) $V_S = 500$ Volts; I_T (Initiating Current) = ± 1.0 Amp (+65°C)	I _H	150 130	270 -	- -	mA
Critical Rate of Rise of Off–State Voltage (Linear waveform, V_D = Rated V_{BR} , T_J = 25°C)	dv/dt	2000	-	-	V/µs
Capacitance (f = 1.0 MHz, 50 Vdc, 1.0 V rms Signal) (f = 1.0 MHz, 2.0 Vdc, 1.0 V rms Signal)	Co	_ _	14 27	18 30	pF

^{3.} Measured under pulse conditions to reduce heating.

Voltage Current Characteristic of TSPD (Bidirectional Device)

Symbol	Parameter
I _{D1} , I _{D2}	Off State Leakage Current
V_{D1}, V_{D2}	Off State Blocking Voltage
V_{BR}	Breakdown Voltage
V_{BO}	Breakover Voltage
I _{BO}	Breakover Current
I _H	Holding Current
V_{TM}	On State Voltage





400 V_{BR}, BREAKDOWN VOLTAGE (VOLTS) 390 380 370 360 350 340 330 320 -60 -40 -20 20 60 80 100 120 140 TEMPERATURE (°C)

Figure 1. Typical Off-State Current versus Temperature

Figure 2. Typical Breakdown Voltage versus Temperature

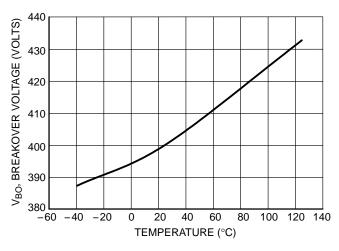


Figure 3. Maximum Breakover Voltage versus Temperature

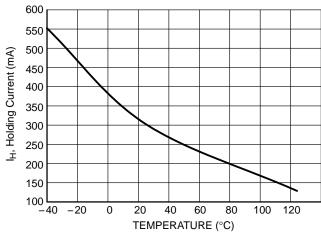


Figure 4. Typical Holding Current versus Temperature

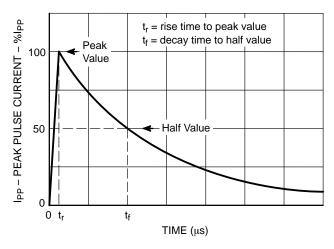


Figure 5. Exponential Decay Pulse Waveform

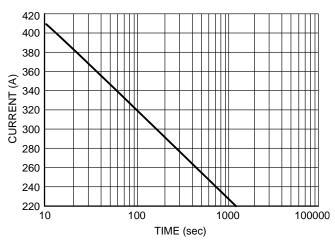
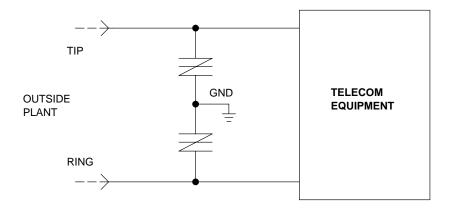
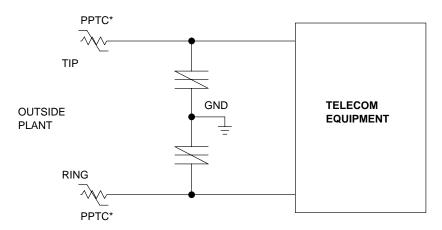
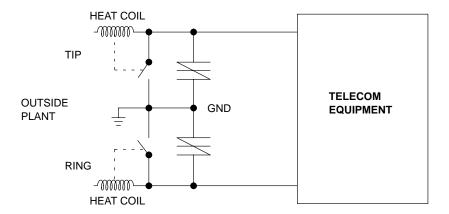


Figure 6. Peak Surge On-State Current versus Surge Current Duration, Sinusoidal Waveform



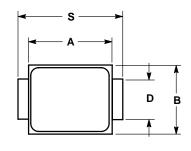


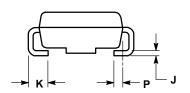
*Polymeric PTC (positive temperature coefficient) overcurrent protection device

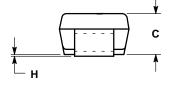


PACKAGE DIMENSIONS

SMB CASE 403C-01 ISSUE O





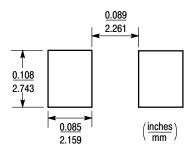


NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH.
- 3. D DIMENSION SHALL BE MEASURED WITHIN DIMENSION P.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.160	0.180	4.06	4.57	
В	0.130	0.150	3.30	3.81	
С	0.075	0.095	1.90	2.41	
D	0.077	0.083	1.96	2.11	
Н	0.0020	0.0060	0.051	0.152	
J	0.006	0.012	0.15	0.30	
K	0.030	0.050	0.76	1.27	
Р	0.020 REF		0.51 REF		
S	0.205	0.220	5.21	5.59	

SOLDERING FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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